



राष्ट्रीय प्रौद्योगिकी संस्थान सिलचर
NATIONAL INSTITUTE OF TECHNOLOGY SILCHAR
अध्यक्ष का कार्यालय (शोध एवं परामर्श)
OFFICE OF THE DEAN (RESEARCH & CONSULTANCY)

Advertisement No.: NITS/Dean(R&C)/ Physics /697/02/2026**Date: 07.09.2026**

Applications are invited from Indian citizens for a temporary of post of **Project Associate-I** for the ANRF sponsored project in the **Department of Physics, NIT Silchar**.

Title of the project	Exploring novel transport induced by quantum geometry in unconventional superconductors
Sponsored Agency	Anusandhan National Research Foundation (ANRF)
Project sanction number	ANRF/ECRG/2024/005947/PMS
No. of posts	One (01)
Duration	12 months initially and extendable until project completion subject to availability of funds and performance review
Principal Investigator (P.I)	Dr. Snehasish Nandy

General Information and Terms & Conditions

1. Age Limit	30 years (on last date of advertisement)
2. Essential Qualification	MSc. in Physics or BS-MS in Physics
3. Desirable Experience	Basic knowledge in condensed matter physics.
4. Salary	(i) Rs.37,000/- + HRA to Scholars who are selected through: (a) National Eligibility Tests, CSIR-UGC NET including Lectureship (Assistant Professorship) or GATE or (b) A selection process through National Level examinations conducted by Central Government Departments and their Agencies and Institutions. (ii) Rs.30,000/- + HRA for others who do not fall under (i) above. Note: Candidate will be eligible for H.R.A as per the Project/Institute norms.
5. Relaxation on qualification and age	Relaxation as per Govt. of India Rules.
6. Last date of receiving of filled up application form (soft-copy)	Applications received by 21st September 2026 will be given priority. The position will remain open until filled.
7. Process to Apply	Applicants are requested to send the soft copy of the duly filled application form (given below) along with C.V. & soft copy of all supporting documents to the PI through the email (snehasish@phy.nits.ac.in), with the subject line: "Application for the post of Project Associate-I under the ANRF/ECRG/2024/005947/PMS" . For any queries, Contact PI at: 9609850979
8. Date of interview, time, and venue	Interview date and mode (online/ offline) with other details will be duly notified through email. NB: No TA/DA will be paid for appearing in the interview and/or Joining to the post. All the terms & conditions for this recruitment will be as per the guidelines of the sponsoring agency and NIT Silchar
9. No objection certificate	Employed candidates are to submit no objection certificate from his/her employer at the time of interview.
10. Institute right	The Institute has the discretion to restrict the number of candidates to be called for the interview on the basis of screening. No candidate may be recruited if suitable candidates are not found.
11. Signing of the agreement	Selected candidates shall have to sign an agreement at the time of joining.

Sd/

Associate Dean (R&C)
NIT Silchar.-

National Institute of Technology Silchar
FORMAT of APPLICATION
For Junior Research Fellow

Annexure 01(A) - 2

Paste recent
passport
size colored
photograph

1. Advertisement no. dated:
2. Title of the Project-
.....
3. Department:
4. Name of the applicant (in block letters):
5. Father's/Husband's Name:
6. Date of Birth (DD-MM-YYYY):
7. Age as on **21.09.2026**:
8. Postal Address:

E-mail:

Phone no.:

9. Permanent Address:
10. Nationality:
11. Marital Status:
12. Whether belongs to SC/ST/OBC/EWS:(If yes, attach certificate):

13. Educational Qualification:(Starting from Class X)

Exam. passed	Board/Univers ity	Division	% age of marks/ CPI	Year of passing	Subjects

14. NET/GATE Examinations Passed:

I. NET				II. GATE		
Subject	Score	Valid upto		Subject	Score	Valid upto

15. Details of employments:

Sl.No.	Name of the Organization	Name of the post	Period	Scale of pay and present pay	Nature of duty

16. Any other relevant information that you may like to furnish:

Declaration

I declare that the above information are true and correct to the best of my knowledge and belief.

Date:

Place

Signature of the applicant